

VOIDLESS-HERMETICALLY SEALED SURFACE Qualified Levels: RoHS JA<mark>N, JANTX, JAN</mark>TXV Available on MOUNT FAST RECOVERY GLASS RECTIFIERS and JANS commercial versions Qualified per MIL-PRF-19500/411 DESCRIPTION This "fast recovery" rectifier diode series is military qualified and is ideal for high-reliability applications where a failure cannot be tolerated. These industry-recognized 3.0 Amp rated rectifiers for working peak reverse voltages from 50 to 600 volts are hermetically sealed with voidless-glass construction using an internal "Category 1" metallurgical bond. These devices are also available in axial-leaded packages for thru-hole mounting. Microsemi also offers numerous other rectifier products to meet higher and lower current ratings with various recovery time speed requirements including fast and ultrafast device types in both through-hole and surface mount packages. "B" MELF or D-5B Important: For the latest information, visit our website http://www.microsemi.com. **FEATURES** Package Surface mount equivalent of JEDEC registered 1N5415 thru 1N5420 series. . Voidless hermetically sealed glass package. Quadruple-layer passivation. Internal "Category 1" Metallurgical bonds. Also available in: Working Peak Reverse Voltage 50 to 600 Volts. JAN, JANTX, JANTXV and JANS qualification per MIL-PRF-19500/411 available. "B" Package (axial-leaded) RoHS compliant versions available (commercial grade only). 🔁 <u>1N5415 – 1N5420</u> **APPLICATIONS / BENEFITS** Fast recovery 3 Amp rectifiers 50 to 600 V. Military and other high-reliability applications. General rectifier applications including bridges, half-bridges, catch diodes, etc. High forward surge current capability. Extremely robust construction. Low thermal resistance. Controlled avalanche with peak reverse power capability. Inherently radiation hard as described in Microsemi "MicroNote 050". MAXIMUM RATINGS Symbol **Parameters/Test Conditions** Value Unit °C Junction and Storage Temperature T_J and T_{STG} -65 to +175 Thermal Resistance Junction-to-End Cap $R_{\Theta JEC}$ 6.5 °C/W Forward Surge Current @ 8.3 ms half-sine I_{FSM} 80 А I₀ ^(1, 2) Average Rectified Forward Current (3) @ $T_A = 55 \,^{\circ}C$ 3 А $\tilde{I_0}^{(2)}$ @ $T_A = 100 \,^{\circ}C$ 2 1N5415US Working Peak Reverse Voltage 50 V VRWM MSC – Lawrence 1N5416US 100 6 Lake Street, 1N5417US 200 Lawrence, MA 01841 1N5418US 400 1-800-446-1158 1N5419US 500 (978) 620-2600 1N5420US 600 Fax: (978) 689-0803 1N5415US Maximum Reverse Recovery Time ⁽⁵⁾ 150 trr ns 1N5416US 150 MSC – Ireland 1N5417US 150 Gort Road Business Park, 1N5418US 150 Ennis, Co. Clare, Ireland 1N5419US 250 Tel: +353 (0) 65 6840044 1N5420US 400 Fax: +353 (0) 65 6822298

See notes on next page.

Solder Temperature @ 10 s

T_{SP}

°C

Website:

www.microsemi.com

260



MAXIMUM RATINGS

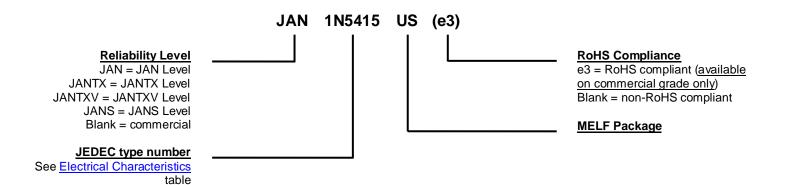
<u>Notes</u>: 1. Derate linearly at 22 mA/°C for 55 °C \leq T_A \leq 100 °C.

- 2. Above $T_A = 100$ °C, derate linearly at 26.7 mA/°C to zero at $T_A = 175$ °C.
 - 3. These ambient ratings are for PC boards where thermal resistance from mounting point to ambient is sufficiently controlled where T_{J(max)} does not exceed 175 °C.

MECHANICAL and PACKAGING

- CASE: Hermetically sealed voidless hard glass with Tungsten slugs.
- TERMINALS: End caps are Copper with Tin/Lead (Sn/Pb) finish. Note: Previous inventory had solid Silver with Tin/Lead (Sn/Pb) finish. RoHS compliant matter-Tin is available for commercial grade only.
- MARKING: Cathode band only.
- POLARITY: Cathode indicated by band.
- TAPE & REEL option: Standard per EIA-481-B. Contact factory for quantities.
- WEIGHT: 539 milligrams.
- See Package Dimensions and recommended Pad Layout on last page.

PART NOMENCLATURE



SYMBOLS & DEFINITIONS				
Symbol	Definition			
V _{BR}	Minimum Breakdown Voltage: The minimum voltage the device will exhibit at a specified current.			
V _{RWM}	Working Peak Reverse Voltage: The maximum peak voltage that can be applied over the operating temperature range excluding all transient voltages (ref JESD282-B).			
lo	Average Rectified Output Current: The Output Current averaged over a full cycle with a 50 Hz or 60 Hz sine-wave input and a 180 degree conduction angle.			
VF	Maximum Forward Voltage: The maximum forward voltage the device will exhibit at a specified current.			
I _R	Maximum Reverse Current: The maximum reverse (leakage) current that will flow at the specified voltage and temperature.			
t _{rr}	Reverse Recovery Time: The time interval between the instant the current passes through zero when changing from the forward direction to the reverse direction and a specified decay point after a peak reverse current occurs.			



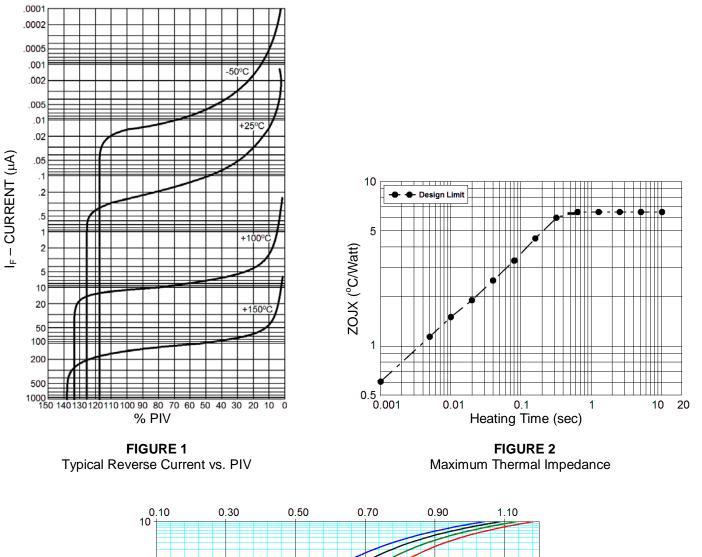
ТҮРЕ	MINIMUM BREAKDOWN VOLTAGE V _{BR} @ 50 μA Volts	FORWARD VOLTAGE V _F @ 9 A		MAXIMUM REVERSE CURRENT I _R @ V _{RWM}		CAPACITANCE C V _R @ 4 V
		MIN. Volts	MAX. Volts	25 °C μΑ	100 °C μΑ	pF
1N5415US	55	0.6	1.5	1.0	20	550
1N5416US	110	0.6	1.5	1.0	20	430
1N5417US	220	0.6	1.5	1.0	20	250
1N5418US	440	0.6	1.5	1.0	20	165
1N5419US	550	0.6	1.5	1.0	20	140
1N5420US	660	0.6	1.5	1.0	20	120

ELECTRICAL CHARACTERISTICS

NOTE 1: I_F = 0.5 A, I_{RM} = 1 A, $I_{R(REC)}$ = 0.250 A



GRAPHS



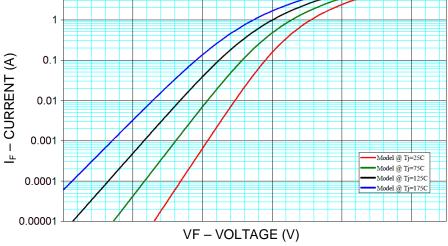
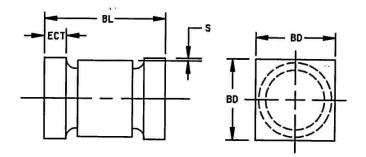


FIGURE 3 Typical Forward Current vs. Forward Voltage



PACKAGE DIMENSIONS

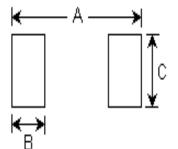


	INC	СН	MILLIMETERS		
	MIN	MAX	MIN	MAX	
BL	0.200	0.225	5.08	5.72	
BD	0.137	0.148	3.48	3.76	
ECT	0.019	0.028	0.48	0.71	
S	0.003		0.08		

NOTES:

- 1. Dimensions are in inches.
- 2. Millimeter equivalents are given for general information only.
- 3. Dimensions are pre-solder dip.
- 4. Minimum clearance of glass body to mounting surface on all orientations.
- 5. In accordance with ASME Y14.5M, diameters are equivalent to Φx symbology.
- 6. This Package Outline has also previously been identified as "D-5B"

PAD LAYOUT



	INCH	MILLIMETERS				
Α	0.288	7.32				
В	0.070	1.78				
С	0.155	3.94				
Note: If mounting requires adhesive						
separate from the solder, an additional						
0.080 inch diameter contact may be						
placed in the center between the pads						
as an optional spot for cement.						